

## HMC431LP4E

Data Sheet

RF Amp Chip Single Buffer Amp 6.1GHz 3.5V 24-Pin QFN EP T/R

Manufacturers Analog Devices, Inc

Package/Case QFN-24

Product Type RF Integrated Circuits

RoHS Pb-free Halide free

Lifecycle



Images are for reference only

Please submit RFQ for HMC431LP4E or Email to us: sales@ovaga.com We will contact you in 12 hours.

**RFO** 

## **General Description**

The HMC431LP4(E) is a GaAs InGaP Heterojunction Bipolar Transistor (HBT) MMIC VCO with an integrated resonator, negative resistance device, varactor diode, and buffer amplifier. The VCO's phase noise performance is excellent over temperature, shock, vibration and process due to the oscillator's monolithic structure. Power output is 2 dBm typical from a 3V supply voltage. The voltage controlled oscillator is packaged in a low cost leadless QFN 4x4 mm surface mount package.

Features Application

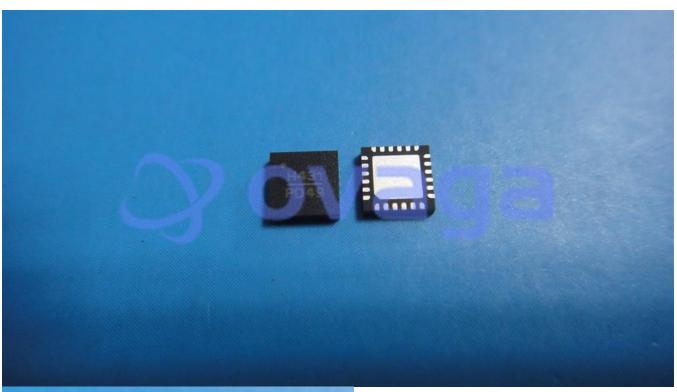
Pout: +2 dBm 802.11a & HiperLAN WLAN

Phase Noise: -102 dBc/Hz @100 kHz VSAT Radios

No External Resonator Needed UNII & Point-to-Point Radios

Single Supply: 3V @ 27 mA

16mm<sup>2</sup> Leadless SMT Package





## **Related Products**



HMC3653LP3BE Analog Devices, Inc QFN-12



HMC253AQS24 Analog Devices, Inc 24-SSOP (0.154, 3.90mm Width)



QFN-16 HMC948LP3E Analog Devices, Inc LP3

Analog Devices, Inc

HMC441LP3E





HMC358MS8GE Analog Devices, Inc MSOP-8



HMC453ST89E

Analog Devices, Inc
ST89E



Analog Devices, Inc SMD

**HMC490** 



HMC618ALP3E
Analog Devices, Inc
QFN-16